

# **HL6333MG/34MG**

# Low Operating Current Visible Laser Diode

ODE2017-00 (M) Rev.0 Aug. 01, 2008

#### **Description**

The HL6333MG/34MG are 0.63  $\mu$ m band AlGaInP 10mW laser diodes with a multi-quantum well (MQW) structure. They are suitable as light sources for laser levelers, laser scanners and optical equipment for measurement.

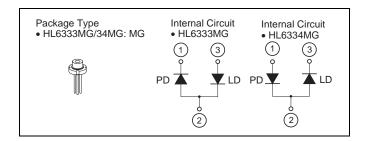
#### **Features**

• Visible light output:  $\lambda p = 635 \text{ nm Typ}$ 

Single longitudinal mode

Optical output power: 10 mW CW
 Low operating current: 55 mA Typ
 Low Operating voltage: 2.4 V Max
 Operating temperature: +50°C

• TM mode oscillation



## **Absolute Maximum Ratings**

 $(T_C = 25^{\circ}C)$ 

Item	Symbol Ratings		Unit
Optical output power	Po	10	mW
LD reverse voltage	$V_{R(LD)}$	2	V
PD reverse voltage	$V_{R(PD)}$	30	V
Operating temperature	Topr	-10 to +50	°C
Storage temperature	Tstg	-40 to +85	°C

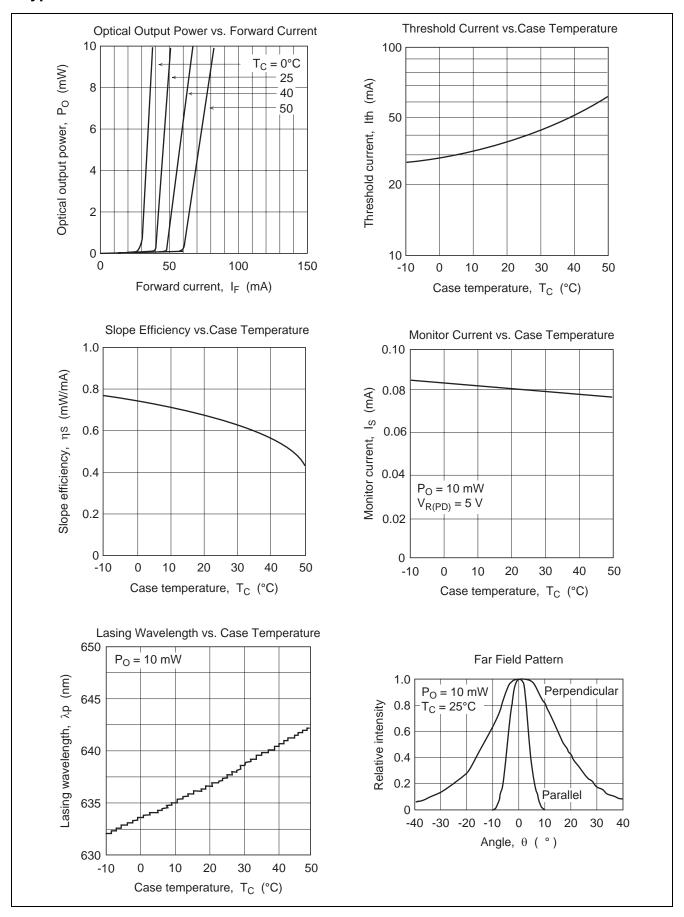
### **Optical and Electrical Characteristics**

 $(T_C = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	Ith	_	40	60	mA	_
Operating current	I <sub>Op</sub>	_	55	75	mA	P <sub>O</sub> = 10 mW
Operating voltage	V <sub>OP</sub>	_	2.2	2.4	V	P <sub>O</sub> = 10 mW
Slope efficiency	ης	0.40	0.65	0.90	mW/mA	6 (mW) / (I <sub>(8mW)</sub> – I <sub>(2mW)</sub> )
Beam divergence parallel to the junction	θ//	6	8	11	0	P <sub>O</sub> = 10 mW
Beam divergence perpendicular to the junction	θΤ	25	31	36	٥	P <sub>O</sub> = 10 mW
Lasing wavelength	λр	630	635	640	nm	P <sub>O</sub> = 10 mW
Monitor current	Is	0.04	0.08	0.16	mA	$P_{O} = 10 \text{ mW}, V_{R(PD)} = 5 \text{ V}$



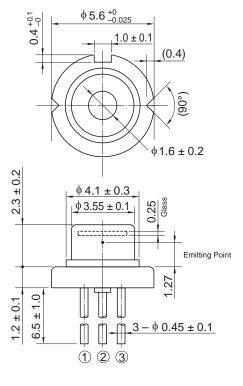
### **Typical Characteristic Curves**

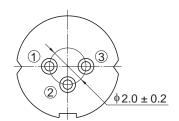


# **Package Dimensions**

As of July, 2002 Unit: mm







OPJ Code	LD/MG
JEDEC	_
JEITA	_
Mass (reference value)	0.3 g

#### **Cautions**

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  - When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.
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#### **Sales Offices**



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